MPSA64 is a Preferred Device

Darlington Transistors

PNP Silicon

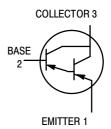
Features

• Pb-Free Packages are Available*



ON Semiconductor®

http://onsemi.com



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage MPSA62 MPSA63/64	V _{CES}	-20 -30	Vdc
Collector – Base Voltage MPSA62 MPSA63/64	V _{CBO}	-20 -30	Vdc
Emitter – Base Voltage	V _{EBO}	-10	Vdc
Collector Current – Continuous	I _C	-500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

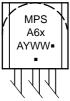
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

MARKING DIAGRAM





= 2, 3, or 4

A = Assembly Location Y = Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS		•	•		
Collector – Emitter Breakdown Voltage ($I_C = -100 \mu Adc$, $V_{BE} = 0$)	MPSA62 MPSA63, MPSA64	V _{(BR)CES}	-20 -30	_ _	Vdc
Collector Cutoff Current $(V_{CB} = -15 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -30 \text{ Vdc}, I_E = 0)$	MPSA62 MPSA63, MPSA64	I _{CBO}	- -	-100 -100	nAdc
Emitter Cutoff Current $(V_{EB} = -10 \text{ Vdc}, I_C = 0)$		I _{EBO}	-	-100	nAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain $(I_C = -10 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$ $(I_C = -100 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	MPSA63 MPSA64 MPSA62 MPSA63	h _{FE}	5,000 10,000 20,000 10,000	- - -	_
Collector – Emitter Saturation Voltage ($I_C = -10$ mAdc, $I_B = -0.01$ mAdc) ($I_C = -100$ mAdc, $I_B = -0.1$ mAdc)	MPSA64 MPSA62 MPSA63, MPSA64	V _{CE(sat)}	20,000	-1.0 -1.5	Vdc
Base – Emitter On Voltage ($I_C = -10$ mAdc, $V_{CE} = -5.0$ Vdc) ($I_C = -100$ mAdc, $V_{CE} = -5.0$ Vdc)	MPSA62 MPSA63, MPSA64	V _{BE(on)}		-1.4 -2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS		•	•		•
Current-Gain — Bandwidth Product (Note 2) (I _C = -100 mAdc, V _{CE} = -5.0 Vdc, f = 100 MHz)	MPSA63, MPSA64	f _T	125	_	MHz

^{1.} Pulse Test: Pulse Width \leq 300 μ s; Duty Cycle \leq 2.0%. 2. $f_T = |h_{fe}| \bullet f_{test}$.

ORDERING INFORMATION

Device	Package	Shipping [†]
MPSA62	TO-92	5000 Units / Bulk
MPSA63	TO-92	5000 Units / Bulk
MPSA63G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSA63RLRA	TO-92	2000 / Tape & Reel
MPSA63RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA63RLRM	TO-92	2000 / Ammo Pack
MPSA63RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA63RLRP	TO-92	2000 / Ammo Pack
MPSA63RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA63ZL1	TO-92	2000 / Ammo Pack
MPSA63ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA64	TO-92	5000 Units / Bulk
MPSA64G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSA64RLRA	TO-92	2000 / Tape & Reel
MPSA64RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA64RLRM	TO-92	2000 / Ammo Pack
MPSA64RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

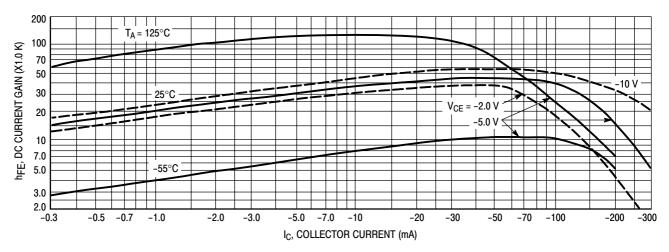


Figure 1. DC Current Gain

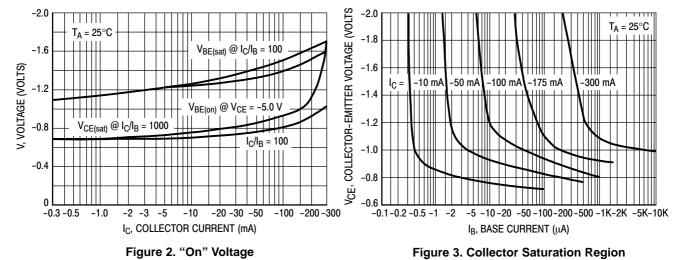


Figure 2. "On" Voltage

IhFE), HIGH FREQUENCY CURRENT GAIN

4.0 3.0

2.0

1.0

0.2

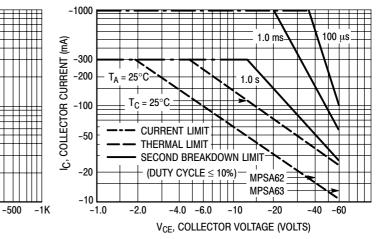
-1.0 -2.0

V_{CE} =

f = 100 MHz

T_A = 25°C

-5.0 V



IC, COLLECTOR CURRENT (mA) Figure 4. High Frequency Current Gain

-20

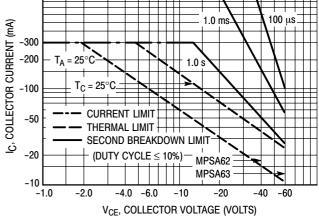
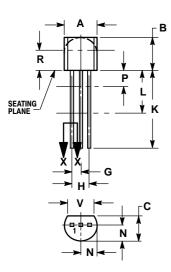


Figure 5. Active Region, Safe Operating Area

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
L	0.015	0.020	0.39	0.50
K	0.500		12.70	
Г	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1:

PIN 1. EMITTER

2. BASE 3. COLLECTOR

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